NSN 5961-00-448-5113

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View Online at https://aerobasegroup.com/nsn/5961-00-448-5113 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Electrode Internally-electrically Connected To Case:** Source **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 drain to gate voltage and 20.0 drain to source voltage and -6.0 reverse gate to source voltage **Current Rating Per Characteristic:** 50.00 milliamperes drain current and 1.00 milliamperes gate 1 current and 1.00 milliamperes gate 2 current and 1.00 milliamperes reverse gate current **Power Rating Per Characteristic:** 330.0 milliwatts total device dissipation **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 80131-release6201 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: